



Changshu Talent  
Semiconductors Co.,Ltd  
Tel:0086-512-52851998  
Fax:0086-512-52153129

# 1N4001GP THRU 1N4007GP

## Features

- Glass Passivated Junction
- Low Current Leakage and Low Cost
- Lead Free Finish/Rohs Compliant (Note1)
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1

## Maximum Ratings

- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Maximum Thermal Resistance; 20 °C/W Junction To Lead

Catalog Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
1N4001GP	1N4001GP	50V	35V	50V
1N4002GP	1N4002GP	100V	70V	100V
1N4003GP	1N4003GP	200V	140V	200V
1N4004GP	1N4004GP	400V	280V	400V
1N4005GP	1N4005GP	600V	420V	600V
1N4006GP	1N4006GP	800V	560V	800V
1N4007GP	1N4007GP	1000V	700V	1000V

## Electrical Characteristics @ 25°C Unless Otherwise Specified

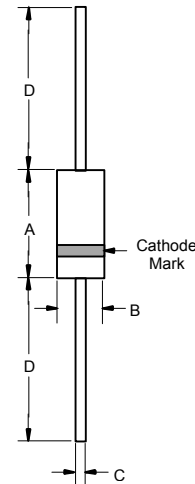
Average Forward Current	$I_{F(AV)}$	1.0A	$T_A = 75^\circ\text{C}$
Peak Forward Surge Current	$I_{FSM}$	30A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	$V_F$	1.1V	$I_{FM} = 1.0\text{A}; T_J = 25^\circ\text{C}^*$
Maximum DC Reverse Current At Rated DC Blocking Voltage	$I_R$	5.0 $\mu\text{A}$ 50 $\mu\text{A}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$
Typical Junction Capacitance	$C_J$	15pF	Measured at 1.0MHz, $V_R=4.0\text{V}$
Maximum Reverse Recovery Time	$T_{rr}$	2.0us	$I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$

\*Pulse test: Pulse width 300  $\mu\text{sec}$ , Duty cycle 2%

Note: 1. High Temperature Solder Exemption Applied, see EU Directive Annex 7.

## 1 Amp Glass Passivated Rectifier 50 - 1000 Volts

### DO-41

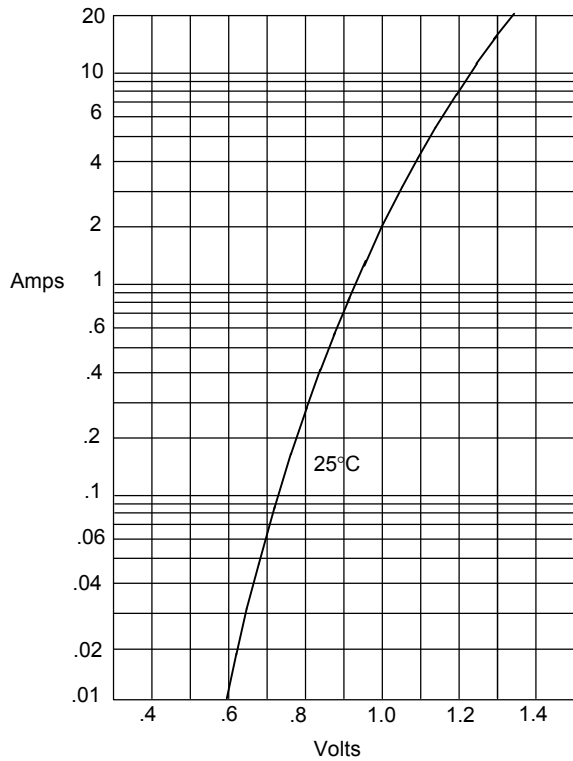


DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.166	.205	4.10	5.20	
B	.080	.107	2.00	2.70	
C	.028	.034	.70	.90	
D	1.000	---	25.40	---	

# 1N4001GP thru 1N4007GP

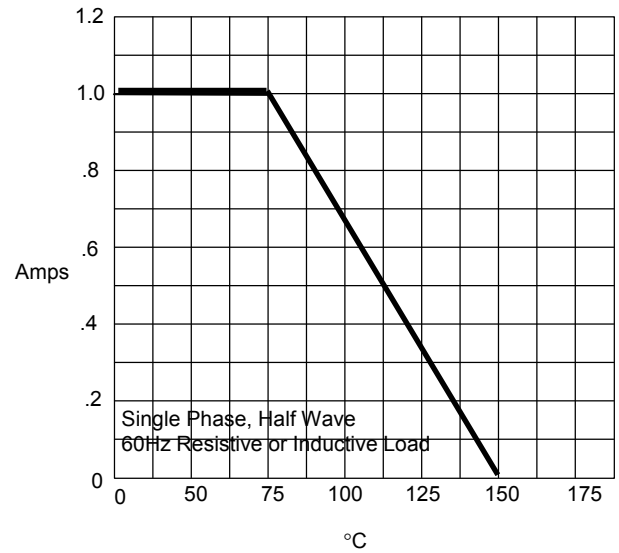


Figure 1  
Typical Forward Characteristics



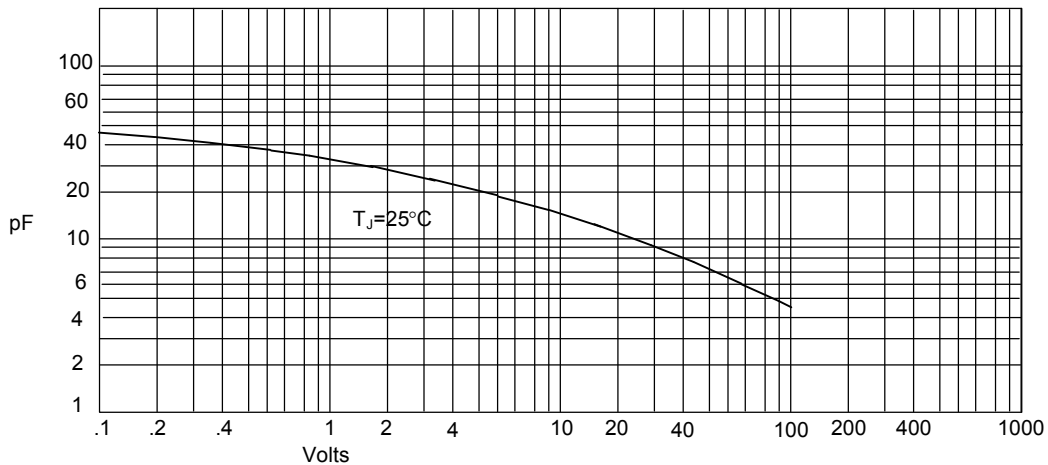
Instantaneous Forward Current - Amperes *versus*  
Instantaneous Forward Voltage - Volts

Figure 2  
Forward Derating Curve



Average Forward Rectified Current - Amperes *versus*  
Ambient Temperature - °C

Figure 3  
Junction Capacitance

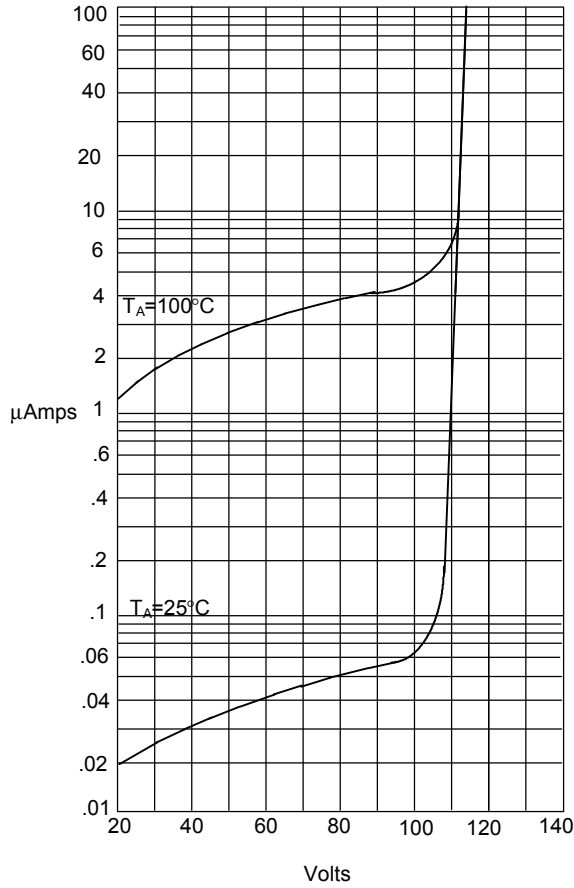


Junction Capacitance - pF *versus*  
Reverse Voltage - Volts

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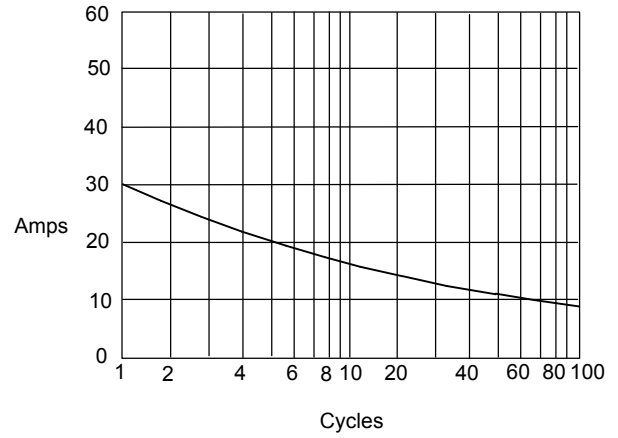


Figure 4  
Typical Reverse Characteristics



Instantaneous Reverse Leakage Current - MicroAmperes versus  
Percent Of Rated Peak Reverse Voltage - Volts

Figure 5  
Peak Forward Surge Current



Peak Forward Surge Current - Amperes versus  
Number Of Cycles At 60Hz - Cycles